40V LOW $V_{CE(sat)}$ PNP SURFACE MOUNT TRANSISTOR

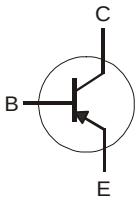
Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Ultra Small Surface Mount Package
- **"Lead Free", RoHS Compliant (Note 1)**
- **Halogen and Antimony Free, "Green Device" (Note 2)**
- **ESD rating: 400V-MM, 8KV-HBM**

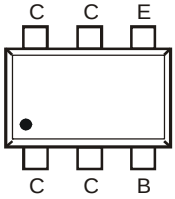
Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin annealed over Copper Plated Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.006 grams (approximate)

Top View



Device Symbol



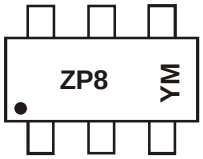
Top View
Pin Out Configuration

Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS5240Y-7	ZP8	7	8mm	3,000

Notes:
1. No purposefully added lead.
2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
3. For packaging details, go to our website at http://www.diodes.com

Marking Information



ZP8 = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: W = 2009)
M = Month (ex: 9 = September)

Date Code Key

Year	2009	2010	2011	2012	2013	2014	2015	2016
Code	W	X	Y	Z	A	B	C	D

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-40	V
Collector-Emitter Voltage	V_{CEO}	-40	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current - Continuous	I_C	-2	A
Peak Pulse Collector Current	I_{CM}	-3	A
Base Current (DC)	I_B	-300	mA
Peak Base Current	I_{BM}	-1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4) @ T_A = 25°C	P_D	625	mW
Thermal Resistance, Junction to Ambient (Note 4) @ T_A = 25°C	$R_{\theta JA}$	200	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes: 4. Device mounted on FR-4 PCB, with minimum recommended pad layout.

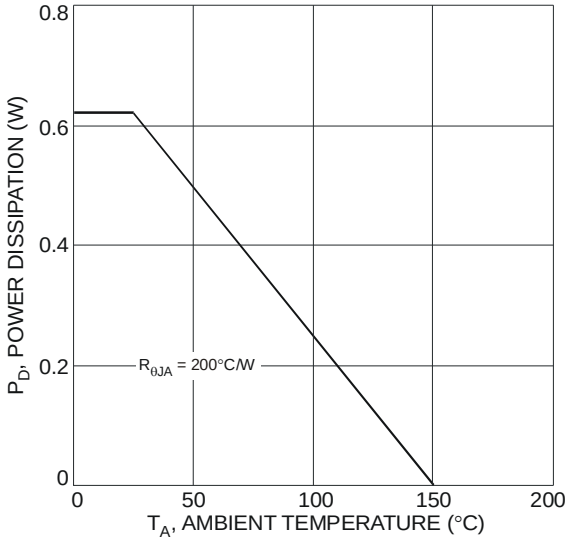

Fig. 1 Power Dissipation vs. Ambient Temperature (Note 4)

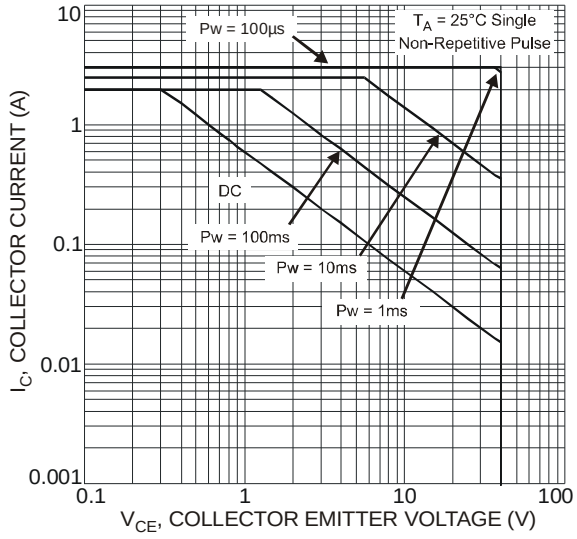

Fig. 2 Safe Operating Area

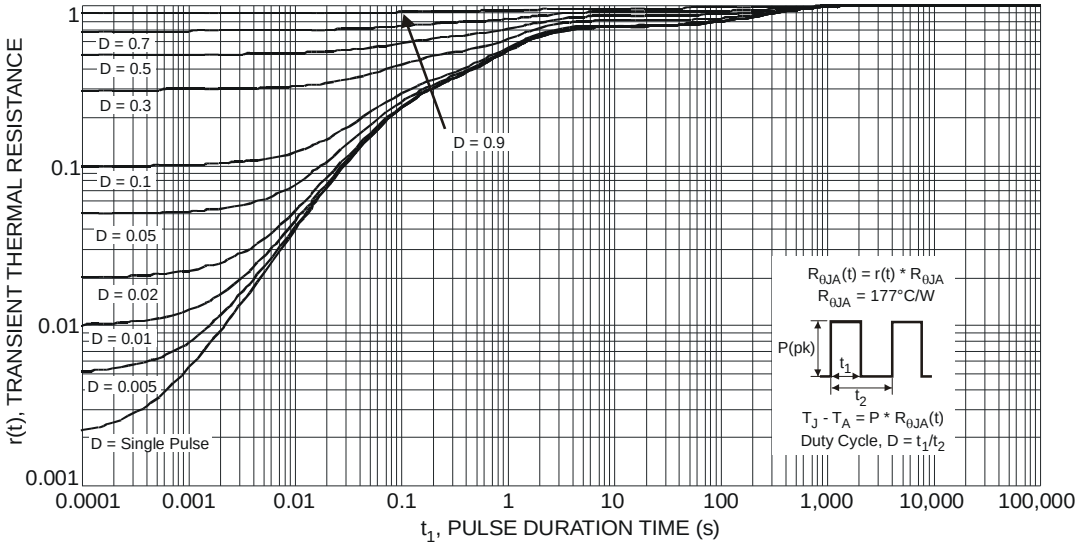

Fig. 3 Transient Thermal Response

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Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-40	—	—	V	I_C = -100μA, I_E = 0
Collector-Emitter Breakdown Voltage (Note 5)	BV_{CEO}	-40	—	—	V	I_C = -10mA, I_B = 0
Emitter-Base Breakdown Voltage	BV_{EBO}	-5	—	—	V	I_E = -100μA, I_C = 0
Collector Cutoff Current	I_{CBO}	—	—	-100 -50	nA μA	V_{CB} = -30V, I_E = 0 V_{CB} = -30V, I_E = 0, T_A = 150°C
Emitter Cutoff Current	I_{EBO}	—	—	-100	nA	V_{EB} = -4V, I_C = 0
DC Current Gain (Note 5)	h_{FE}	300 260 210 100	450 380 325 210	— — — —	—	V_{CE} = -2V, I_C = -100mA V_{CE} = -2V, I_C = -500mA V_{CE} = -2V, I_C = -1A V_{CE} = -2V, I_C = -2A
Collector-Emitter Saturation Voltage (Note 5)	$V_{CE(sat)}$	—	—	-100	mV	I_C = -100mA, I_B = -1mA
		—	—	-110		I_C = -500mA, I_B = -50mA
		—	—	-225		I_C = -750mA, I_B = -15mA
		—	—	-225		I_C = -1A, I_B = -50mA
		—	—	-350		I_C = -2A, I_B = -200mA
Collector-Emitter Saturation Resistance	$R_{CE(sat)}$	—	—	-220	mΩ	I_C = -500mA, I_B = -50mA
Base-Emitter Saturation Voltage (Note 5)	$V_{BE(sat)}$	—	-1.0	-1.1	V	I_C = -2A, I_B = -200mA
Base-Emitter Turn On Voltage (Note 5)	$V_{BE(on)}$	—	-0.67	-0.75	V	V_{CE} = -2V, I_C = -100mA
Output Capacitance	C_{obo}	—	25	40	pF	V_{CB} = -10V, f = 1.0MHz
Current Gain-Bandwidth Product	f_T	100	220	—	MHz	V_{CE} = -10V, I_C = -50mA, f = 100MHz
Turn-On Time	t_{on}	—	73	—	ns	V_{CC} = -10V I_C = -1A, I_{B1} = I_{B2} = -50mA
Delay Time	t_d	—	27	—	ns	
Rise Time	t_r	—	46	—	ns	
Turn-Off Time	t_{off}	—	237	—	ns	
Storage Time	t_s	—	195	—	ns	
Fall Time	t_f	—	42	—	ns	

Notes: 5. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.

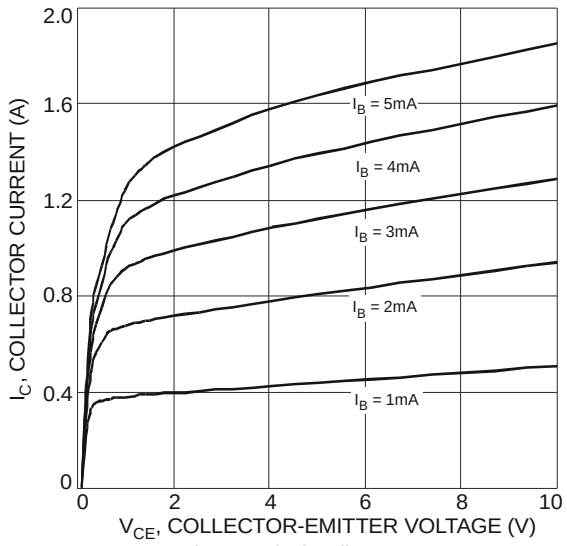

Fig. 4 Typical Collector Current vs. Collector-Emitter Voltage

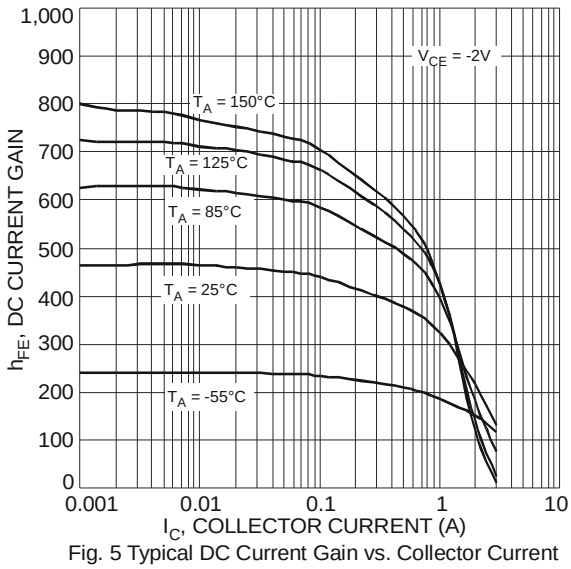

Fig. 5 Typical DC Current Gain vs. Collector Current

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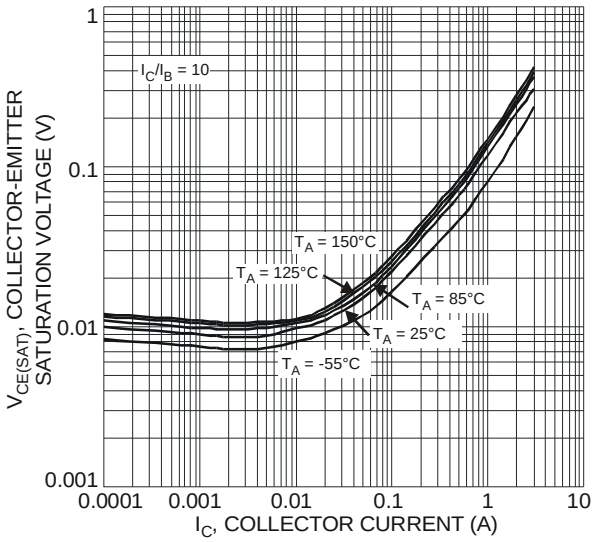

Fig. 6 Typical Collector-Emitter Saturation Voltage vs. Collector Current

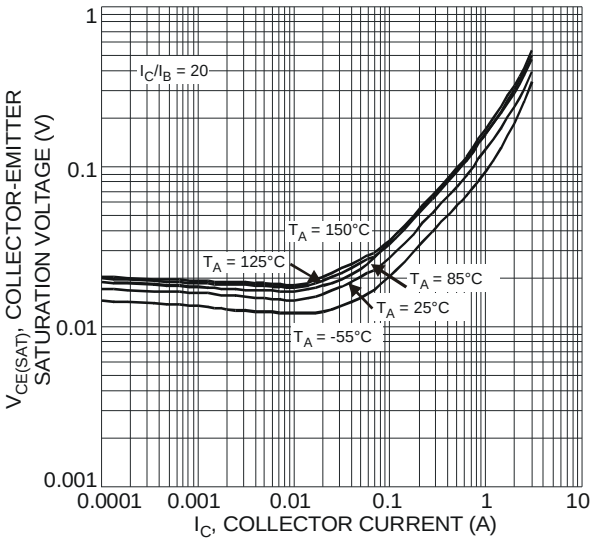

Fig. 7 Typical Collector-Emitter Saturation Voltage vs. Collector Current

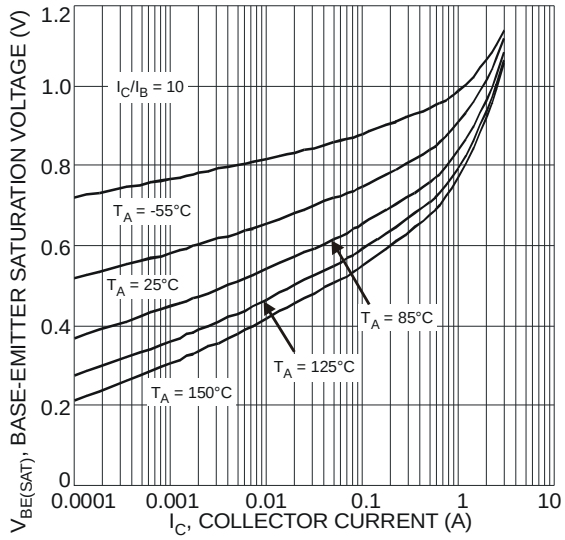

Fig. 8 Typical Base-Emitter Saturation Voltage vs. Collector Current

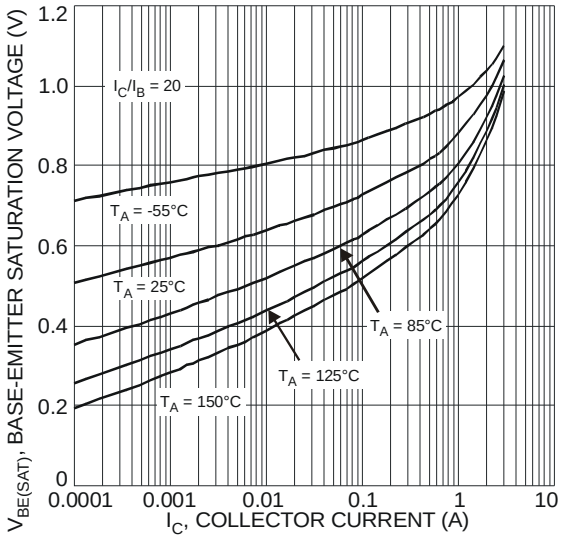

Fig. 9 Typical Base-Emitter Saturation Voltage vs. Collector Current

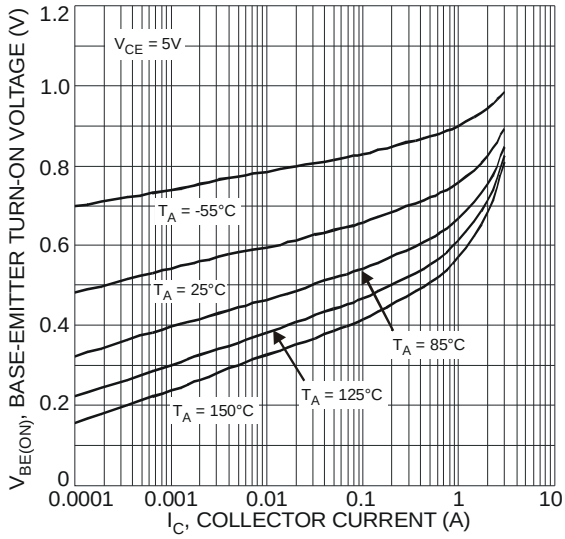

Fig. 10 Typical Base-Emitter Turn-On Voltage vs. Collector Current

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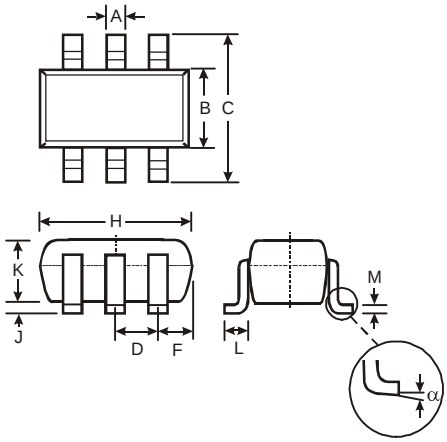
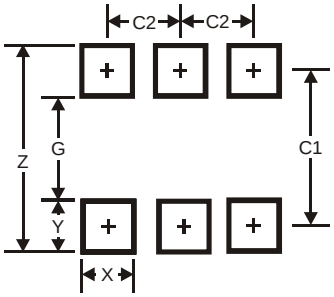
Package Outline Dimensions



SOT-363		
Dim	**Min**	**Max**
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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